

JAN2N1482

JAN2N1482 Information



Part Number	JAN2N1482
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN 55V 1.5A TO-5
Package	TO-205AA, TO-5-3 Metal Can
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



JAN2N1482 Specifications

Manufacturer Part Number	JAN2N1482
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-205AA, TO-5-3 Metal Can
Series	Military, MIL-PRF-19500/207
Transistor Type	NPN
Current - Collector (Ic) (Max)	1.5A
Voltage - Collector Emitter Breakdown (Max)	55V
Vce Saturation (Max) @ Ib, Ic	750mV @ 10mA, 200mA
Current - Collector Cutoff (Max)	5µA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	35 @ 200mA, 4V
Power - Max	1W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-205AA, TO-5-3 Metal Can
Supplier Device Package	TO-5
	Report errors?

JAN2N1482 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about JAN2N1482, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com